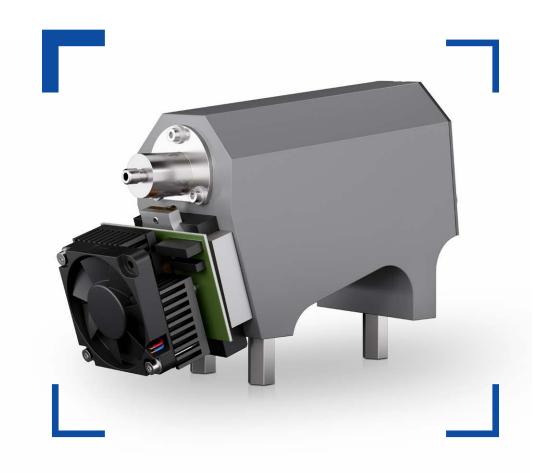
Multi Channel Spectrometer

190-1100 nm



ZEISS MCS Series





195-390 nm



190-780 nm



190-1100 nm



310 – 1100 nm



960 - 2500 nn

Overview

The MCS UV-NIR spectrometer combines a broad coverage within 190–1100 nm with high optical resolution of 3 nm. It employs an aberration corrected concave grating design. As optical input the MCS features a SMA connector with integrated round-to-slit fiber converter for maximizing light collection and system throughput. A ZEISS flat-field grating that enables large acceptance angles with a numerical aperture of 0.22 ensures high imaging quality in the detector plane. Suitable PDA or CCD detector options for highest signal/noise performance or low light level applications are available. All of the optical components are mounted in a housing made of a special alloy (FLEX series) or ceramic material that can be easily customized for OEM solutions. The MCS design and production process ensure thermal stability, low stray light levels and long-term stable calibration leading to reliable measurement results.

- (/) High resolution
- (Fast readout
- **⊘** Long-term calibrated
- (Large NA (0.22)
- High repeatability



Features

The ZEISS MCS has a fiber coupled SMA cross section converter with NA = 0.22 and custom slit, maximizing optical throughput. ZEISS aberration-corrected holographic gratings ensure a flat spectral image of 25 mm. Different materials (ceramics/aluminium) and housing designs are provided. MCS modules are available with PDA arrays for highest SNR > 11.000 or BT-CCD detectors for low-light applications.

Options

- Optical input: SMA cross-section converter / FC connector and / or custom slit 20/40/50/70 µm
- ZEISS gratings with different blaze wavelengths (200/250/300/750 nm)
- Selection of custom spectral coverage within 190−1100 nm
- TE-cooled/uncooled BT-CCD or PDA detector options
- Operating electronics with USB 2.0,
 3.0/Ethernet interface
- ZEISS Aspect Plus software or SDK
- High scalability for volume production

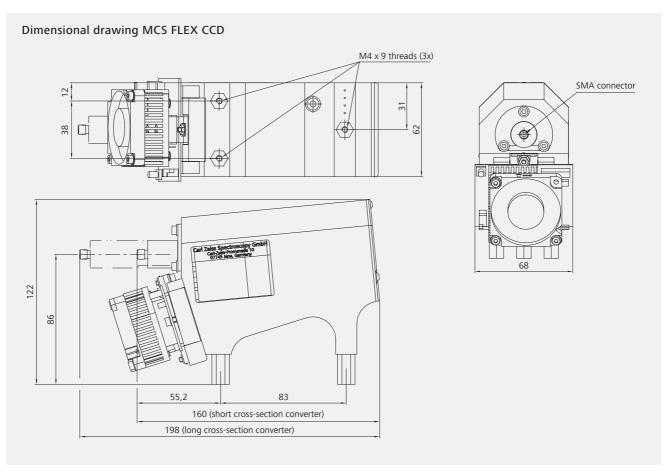
Applications

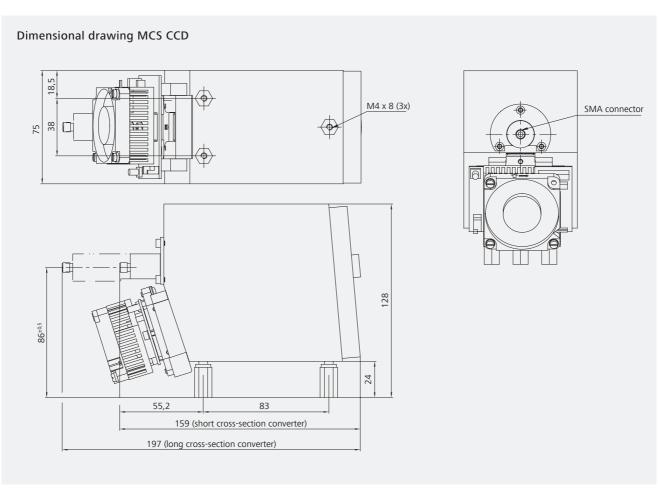
- Thickness measurement: displays, photoresists, dielectric layers, coatings
- Semiconductor: plasma-monitoring, critical dimension measurement, CMP, wafer inspection
- Pharmaceuticals: compound analysis, high pressure liquid chromatography
- Environmental sensors: pollution monitoring, continuous emission monitoring systems
- Food & agriculture: fruit sorting, meat & dairy, plant health monitoring

Specifications

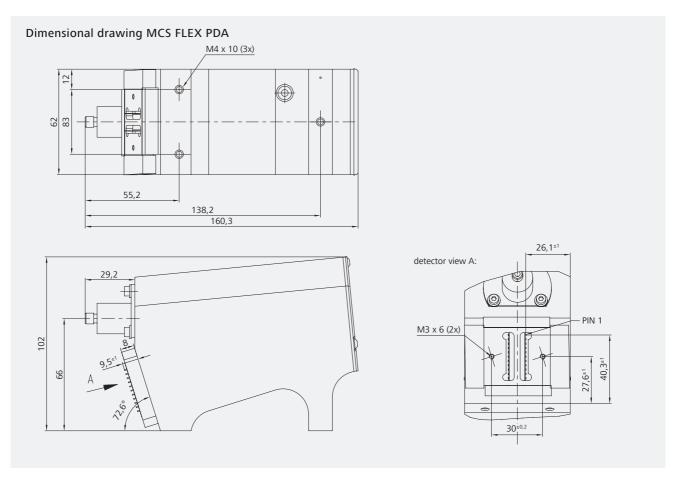
	MCS CCD UV-NIR High (UV) sensitivity, housing of ceramics	MCS FLEX CCD UV-NIR High (UV) sensitivity, housing of alluminium alloy	MCS PDA UV-NIR Exceptional SNR, housing of ceramics	MCS FLEX PDA UV-NIR Exceptional SNR, housing or alluminium alloy
General				
Spectral range	190-	980 nm	190 – 1015 nm	
Resolution (FWHM)	3 nm		3 nm	
Stray light	< 0.1 % (@340 nm, Deuterium lamp, NaNO ₂ 50 g/L, 10 mm)		$<$ 0.1 % (@340 nm, Deuterium lamp, NaNO $_{2}$ 50 g/L, 10 mm)	
Wavelength accuracy	≤ 0	.5 nm	≤ ().3 nm
Temperature drift	< 0.01 nm/K	< 0.009 nm/K	< 0.005 nm/K	< 0.009 nm/K
Optical entrance	(Ø 0.5 mm input, 7	o-slit fiber converter 0 x 1400 μm output), 20/40/50/70 μm)	SMA with round-to-slit fiber converter (Ø 0.5 mm input, 70 x 2400 µm output), optional slit (20/40/50/70 µm)	
Numerical aperture).22	0.22	
Grating	248 l/mm blazed for 250/750 nm	248 l/mm blazed for 250 nm	248 l/mm, blazed for 200/250/750 nm	248 l/mm blazed for 250 nm
Pixel size Signal/noise	24 x 24 μm 1000		25 x 2500 μm 12000	
Electronics (optional) Digitization Integration time Interface	>	oit ADC 3 ms 3.0/Ethernet	16-bit ADC > 1.1 ms USB 2.0, 3.0/Ethernet	
Environmental/physical Operating temperature	0 65 °C (n	on-condensing)	0 65 °C (n	on-condensing)
Dimensions L x W x H	177 x 75 x 128 mm ³	160 x 68 x 122 mm ³ (short fiber converter),	159 x 75 x 108 mm ³	160 x 62 x 102 mm ³

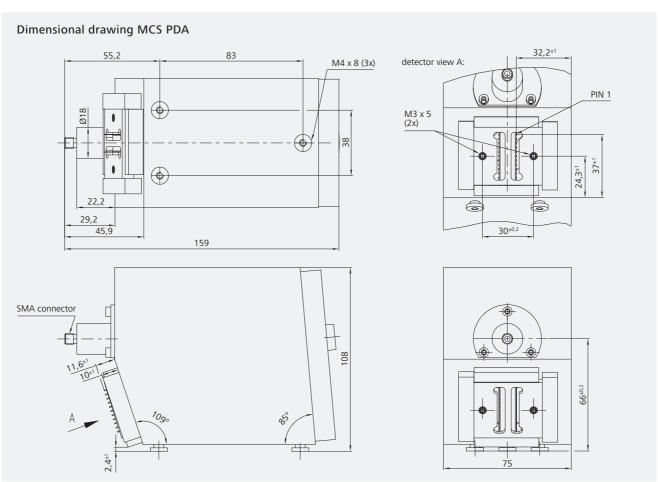
Dimensional drawings





Dimensional drawings





EN_40_010_0013II Printed in Germany CZ-08/2023 Subject to change in design and scope of delivery and as a result of ongoing technical development.

Order information

Spectrometer	Description	Spectral Range	Order Number
MCS PDA UV-NIR	PDA with 1024 pixels, without preamplifier card	190 – 1015 nm	224036-9001-000
MCS PDA UV-NIR	PDA with 1024 pixels, with preamplifier card mounted on MCS with electromagnetic shielding	190 – 1015 nm	000000-2348-729
MCS PDA UV	PDA with 512 pixels, without preamplifier card	200-620 nm	224024-9001-000
MCS PDA UV-VIS	PDA with 512 pixels, without preamplifier card	300-720 nm	224028-9001-000
MCS PDA VIS	PDA with 512 pixels, without preamplifier card	360-780 nm	224020-9001-000
MCS PDA NIR	PDA with 512 pixels, without preamplifier card	695-1100 nm	224032-9001-000
MCS FLEX PDA UV-NIR	PDA with 1024 pixels, without preamplifier card	190 – 1015 nm	000000-1459-276
MCS CCD UV-NIR	Detector Hamamatsu S7031 with 1024 (1044) x 64 pixels, Peltier cooled (TE), incl. cooling body, without sensor board	190-980 nm	000000-1212-556
MCS CCD UV-NIR	CCD Detector Hamamatsu S7031 with 1024 (1044) x 64 pixels, Peltier cooled (TE), incl. cooling body, with mounted sensor board	190-980 nm	000000-2051-588
MCS CCD NIR	CCD Detector Hamamatsu S7031 with 512 (532) x 64 pixels, Peltier cooled (TE), incl. cooling body, without sensor board	600-980 nm	000000-2365-393
MCS CCD NIR	CCD Detector Hamamatsu S7031 with 512 (532) x 64 pixels, Peltier cooled (TE), incl. cooling body, with mounted sensor board	600-980 nm	000000-1292-310
MCS FLEX CCD UV-NIR	CCD Detector Hamamatsu S7031 with 1024 (1044) x 64 pixels, short CSC	190-980 nm	000000-1423-352
MCS FLEX CCD UV-NIR	CCD Detector Hamamatsu S7031 with 1024 (1044) x 64 pixels, long CSC	190-980 nm	000000-1761-535

CSC: Cross-section converter



For questions or order requests please contact us!

Carl Zeiss Spectroscopy GmbH